Using Block SelectRAM™ Memory

Introduction

In addition to distributed SelectRAM memory, Virtex-II devices feature a large number of 18 Kb block SelectRAM memories. The block SelectRAM memory is a True Dual-Port™ RAM, offering fast, discrete, and large blocks of memory in the device. The memory is organized in columns, and the total amount of block SelectRAM memory depends on the size of the Virtex-II device. The 18 Kb blocks are cascadable to enable a deeper and wider memory implementation, with a minimal timing penalty incurred through specialized routing resources.

Embedded dual- or single-port RAM modules, ROM modules, synchronous and asynchronous FIFOs, and data width converters are easily implemented using the Xilinx CORE Generator "Block Memory" modules. Asynchronous FIFOs can also be generated using the CORE Generator Asynchronous FIFO module. Starting with IP Update #3, the designer can also generate synchronous FIFOs using Block Memory.

Synchronous Dual-Port and Single-Port RAM

Data Flow

The 18Kb block SelectRAM dual-port memory consists of an 18-Kb storage area and two completely independent access ports, A and B. The structure is fully symmetrical, and both ports are interchangeable.

Data can be written to either port and can be read from the same or the other port. Each port is synchronous, with its own clock, clock enable, and write enable. Note that the read operation is also synchronous and requires a clock edge.

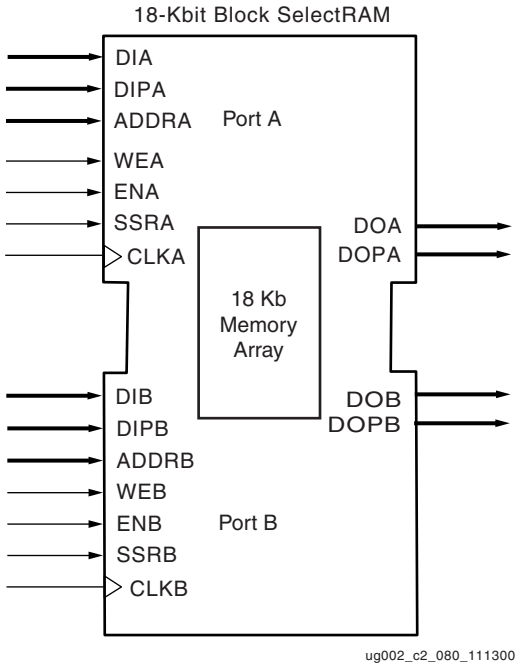

Figure 2-42: **Dual-Port Data Flows**

As described below, there are three options for the behavior of the data output during a write operation on its port. There is no dedicated monitor to arbitrate the result of identical addresses on both ports. It is up to the user to time the two clocks appropriately. However, conflicting simultaneous writes to the same location never cause any physical damage.

Operating Modes

To maximize utilization of the True Dual-Port memory at each clock edge, the block SelectRAM memory supports three different write modes for each port. The "read during write" mode offers the flexibility of using the data output bus during a write operation on the same port. Output behavior is determined by the configuration. This choice increases the efficiency of block SelectRAM memory at each clock cycle and allows designs that use maximum bandwidth.

Read Operation

The read operation uses one clock edge. The read address is registered on the read port, and the stored data is loaded into the output latches after the RAM access interval passes.

Write Operations

A write operation is a single clock-edge operation. The write address is registered on the write port, and the data input is stored in memory.

Three different modes are used to determine data available on the output latches after a write clock edge.

WRITE_FIRST or Transparent Mode (Default)

In WRITE_FIRST mode, the input data is simultaneously written into memory and stored in the data output (transparent write), as shown in Figure 2-43.

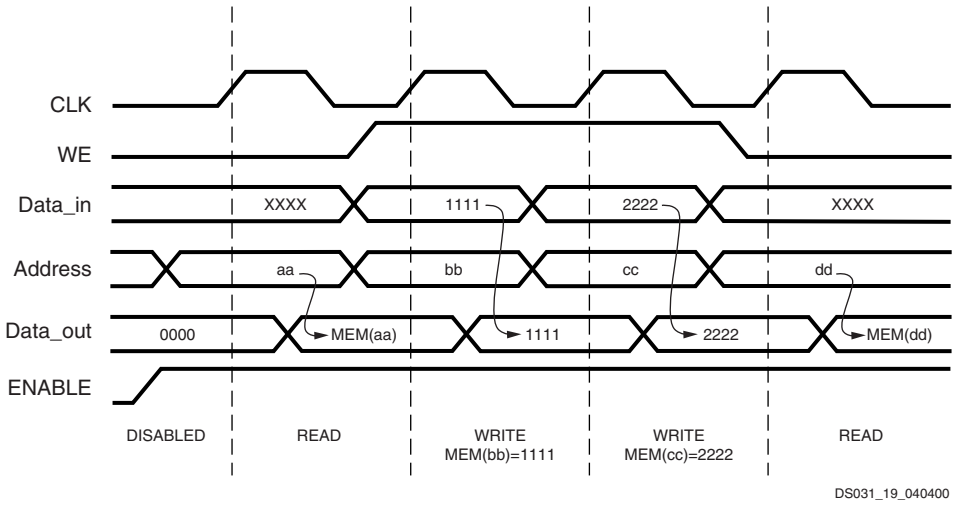

Figure 2-43: **WRITE_FIRST Mode Waveforms**

READ_FIRST or Read-Before-Write Mode

In READ_FIRST mode, data previously stored at the write address appears on the output latches, while the input data is being stored in memory (read before write). See Figure 2-44.

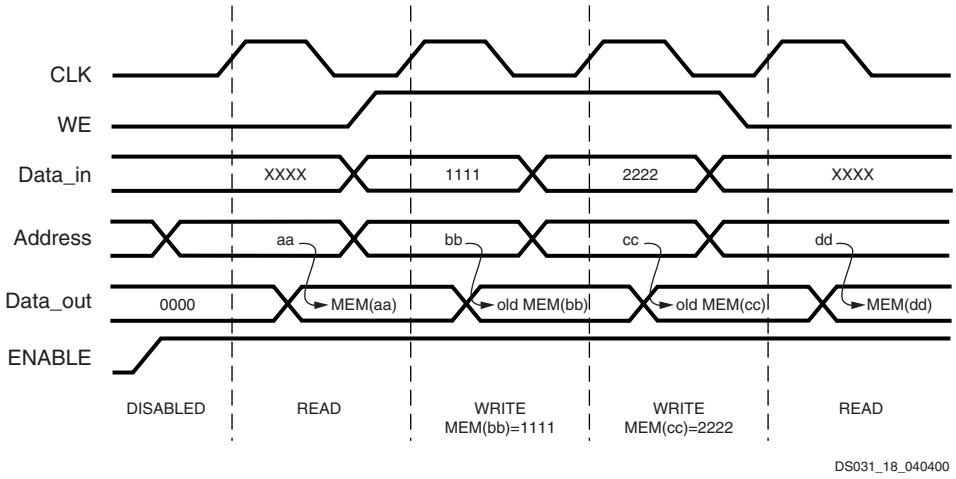

Figure 2-44: **READ_FIRST Mode Waveforms**

NO_CHANGE Mode

In NO_CHANGE mode, the output latches remain unchanged during a write operation. As shown in Figure 2-45, data output is still the last read data and is unaffected by a write operation on the same port.

Mode selection is set by configuration. One of these three modes is set individually for each port by an attribute. The default mode is WRITE_FIRST.

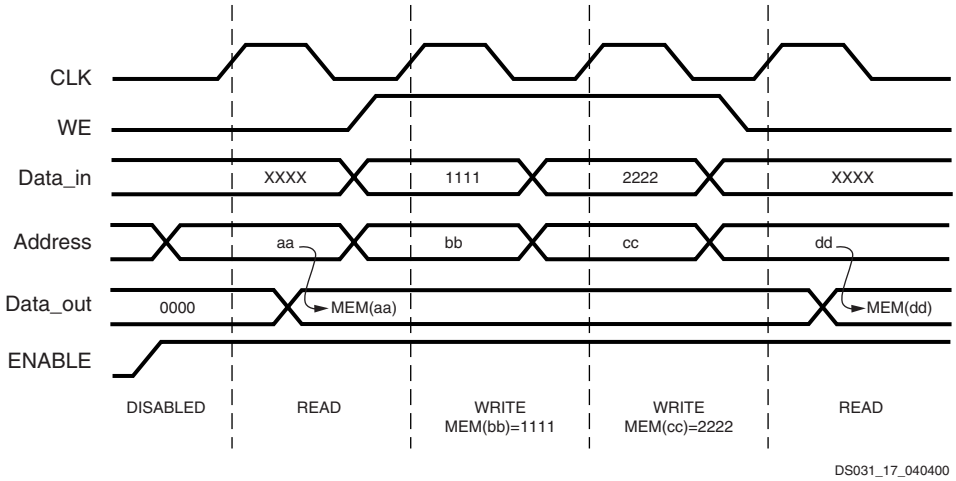

Figure 2-45: **NO_CHANGE Mode Waveforms**

Conflict Resolution

Virtex-II block SelectRAM memory is a True Dual-Port RAM that allows both ports to simultaneously access the same memory cell. When one port writes to a given memory cell, the other port must not address that memory cell (for a write or a read) within the clock-to-clock setup window. Figure 2-46 describes this asynchronous operation.

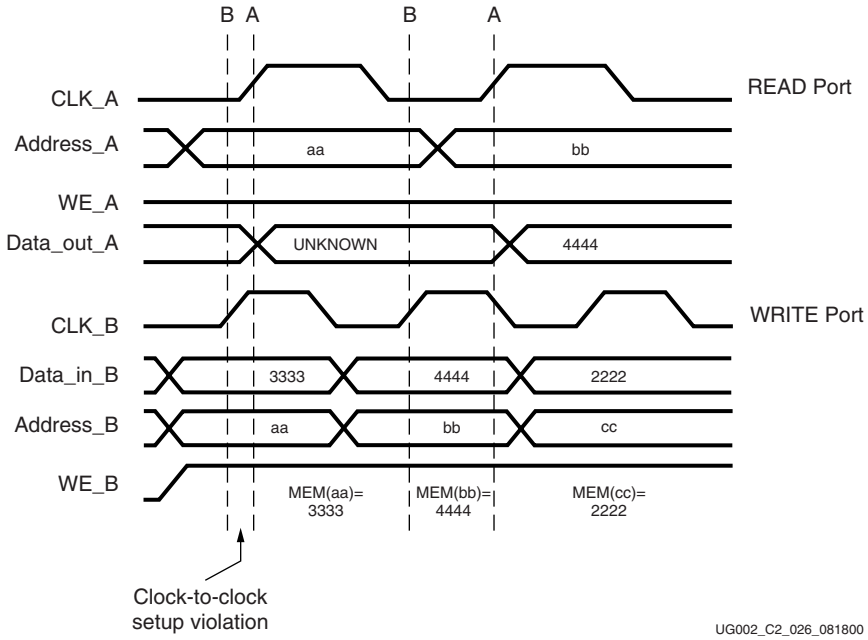

Figure 2-46: **READ-WRITE Conditions**

If port A and port B are configured with different widths, only the overlapping bits are invalid when conflicts occur.

Asynchronous Clocks

The first CLK_A clock edge violates the clock-to-clock setup parameter, because it occurs too soon after the last CLK_B clock edge. The write operation on port B is valid, and the read operation on port A is invalid.

At the second rising edge of the CLK_B pin, the write operation is valid. The memory location (bb) contains 4444. The second rising edge of CLK_A reads the new data at the same location (bb), which now contains 4444.

The clock-to-clock setup timing parameter is specified together with other block SelectRAM switching characteristics in the **Virtex-II Data Sheet**.

Synchronous Clocks

When both clocks are synchronous or identical, the result of simultaneous accesses from both ports to the same memory cell is best described in words:

- If both ports read simultaneously from the same memory cell:
  Both Data_out ports will have the same data.
- If both ports write simultaneously into the same memory cell:
  The data stored in that cell becomes invalid (unless both ports write identical data).
- If one port writes and the other one reads from the same memory cell:
  The write operation succeeds, and the write port's Data_out behaves as determined by the read output mode (write_first, read_first, or no_change).

  If the write port is in read_first mode, the read port's Data_out represents the previous content of the memory cell. If the write port is in write_first mode or in no_change mode, the read port's Data_out becomes invalid. Obviously, the read port's mode setting does not affect this operation.

Characteristics

- A write operation requires only one clock edge.
- A read operation requires only one clock edge.
- All inputs are registered with the port clock and have a setup-to-clock timing specification.
- All outputs have a read-through function or one of three read-during-write functions, depending on the state of the WE pin. The outputs relative to the port clock are available after the clock-to-out timing interval.
- Block SelectRAM cells are true synchronous RAM memories and do not have a combinatorial path from the address to the output.
- The ports are completely independent of each other (that is, clocking, control, address, read/write functions, initialization, and data width) without arbitration.
- Output ports are latched with a self-timed circuit, guaranteeing glitch-free reads. The state of the output port does not change until the port executes another read or write operation.
- Data input and output signals are always busses; that is, in a 1-bit width configuration, the data input signal is DI[0] and the data output signal is DO[0].

Library Primitives

The input and output data busses are represented by two busses for 9-bit width (8+1), 18-bit width (16+2), and 36-bit width (32+4) configurations. The ninth bit associated with each byte can store parity or error correction bits. No specific function is performed on this bit.

The separate bus for parity bits facilitates some designs. However, other designs safely use a 9-bit, 18-bit, or 36-bit bus by merging the regular data bus with the parity bus. Read/write and storage operations are identical for all bits, including the parity bits.

Figure 2-47 shows the generic dual-port block RAM primitive. DIA, DIPA, ADDRA, DOA, DOPA, and the corresponding signals on port B are busses.

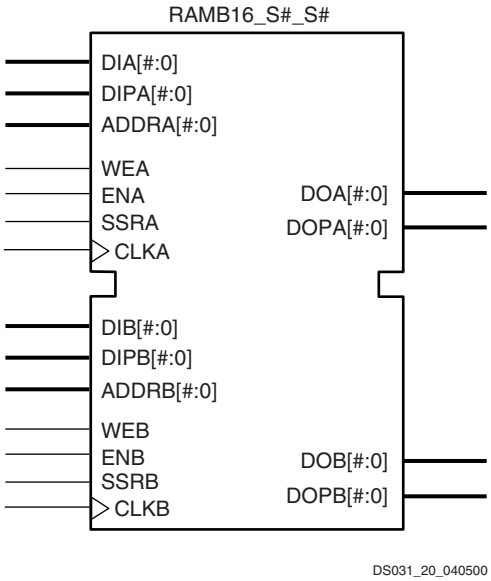

Figure 2-47: **Dual-Port Block RAM Primitive**

Table 2-9 lists the available dual-port primitives for synthesis and simulation.

Table 2-9: **Dual-Port Block RAM Primitives**

Primitive	Port A Width	Port B Width
RAMB16_S1_S1	1	1
RAMB16_S1_S2		2
RAMB16_S1_S4		4
RAMB16_S1_S9		(8+1)
RAMB16_S1_S18		(16+2)
RAMB16_S1_S36		(32+4)
RAMB16_S2_S2	2	2
RAMB16_S2_S4		4
RAMB16_S2_S9		(8+1)
RAMB16_S2_S18		(16+2)
RAMB16_S2_S36		(32+4)
RAMB16_S4_S4	4	4
RAMB16_S4_S9		(8+1)
RAMB16_S4_S18		(16+2)
RAMB16_S4_S36		(32+4)
RAMB16_S9_S9	(8+1)	(8+1)
RAMB16_S9_S18		(16+2)
RAMB16_S9_S36		(32+4)
RAMB16_S18_S18	(16+2)	(16+2)
RAMB16_S18_S36		(32+4)
RAMB16_S36_S36	(32+4)	(32+4)

Figure 2-48 shows the generic single-port block RAM primitive. DI, DIP, ADDR, DO, and DOP are busses.

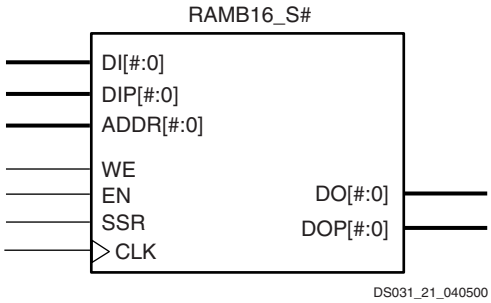

Figure 2-48: **Single-Port Block RAM Primitive**

Table 2-10 lists all of the available single-port primitives for synthesis and simulation.

Table 2-10: **Single-Port Block RAM Primitives**

Primitive	Port Width
RAMB16_S1	1
RAMB16_S2	2
RAMB16_S4	4
RAMB16_S9	(8+1)
RAMB16_S18	(16+2)
RAMB16_S36	(32+4)

VHDL and Verilog Instantiation

VHDL and Verilog instantiation templates are available as examples (see "VHDL and Verilog Templates" on page 207).

In VHDL, each template has a component declaration section and an architecture section. Each part of the template should be inserted within the VHDL design file. The port map of the architecture section should include the design signal names.

The SelectRAM_Ax templates (with x = 1, 2, 4, 9, 18, or 36) are single-port modules and instantiate the corresponding RAMB16_Sx module.

SelectRAM_Ax_By templates (with x = 1, 2, 4, 9, 18, or 36 and y = = 1, 2, 4, 9, 18, or 36) are dual-port modules and instantiate the corresponding RAMB16_Sx_Sy module.

Port Signals

Each block SelectRAM port operates independently of the other while accessing the same set of 18K-bit memory cells.

Clock - CLK[A|B]

Each port is fully synchronous with independent clock pins. All port input pins have setup time referenced to the port CLK pin. The data bus has a clock-to-out time referenced to the CLK pin. Clock polarity is configurable (rising edge by default).

Enable - EN[A|B]

The enable pin affects the read, write, and set/reset functionality of the port. Ports with an inactive enable pin keep the output pins in the previous state and do not write data to the memory cells. Enable polarity is configurable (active High by default).

Write Enable - WE[A|B]

Both EN and WE are active when the contents of the data input bus is written to memory at the address pointed to by the address bus. The output latches are loaded or not loaded according to the write configuration (WRITE_FIRST, READ_FIRST, NO_CHANGE). When inactive, a read operation occurs, and the contents of the memory cells referenced by the address bus reflect on the data-out bus, regardless of the write mode attribute. Write enable polarity is configurable (active High by default).

Set/Reset - SSR[A|B]

The SSR pin forces the data output latches to contain the value "SRVAL" (see "Attributes" on page 205). The data output latches are synchronously asserted to 0 or 1, including the parity bit. In a 36-bit width configuration, each port has an independent SRVAL[A | B] attribute of 36 bits. This operation does not affect RAM memory cells and does not disturb write operations on the other port. Like the read and write operation, the set/reset function is active only when the enable pin of the port is active. Set/reset polarity is configurable (active High by default).

Address Bus - ADDR[A|B]<#:0>

The address bus selects the memory cells for read or write. The width of the port determines the required address bus width, as shown in Table 2-11.

Table 2-11: **Port Aspect Ratio**

Port Data Width	Depth	ADDR Bus	DI Bus / DO Bus	DIP Bus / DOP Bus
1	16,384	<13:0>	<0>	NA
2	8,192	<12:0>	<1:0>	NA
4	4,096	<11:0>	<3:0>	NA
9	2,048	<10:0>	<7:0>	<0>
18	1,024	<9:0>	<15:0>	<1:0>
36	512	<8:0>	<31:0>	<3:0>

Data-In Busses - DI[A|B]<#:0> & DIP[A|B]<#:0>

Data-in busses provide the new data value to be written into RAM. The regular data-in bus (DI) and the parity data-in bus (when available) have a total width equal to the port width. For example the 36-bit port data width is represented by DI<31:0> and DIP<3:0>, as shown in Table 2-11.

Data-Out Busses - DO[A|B]<#:0> & DOP[A|B]<#:0>

Data-out busses reflect the contents of memory cells referenced by the address bus at the last active clock edge during a read operation. During a write operation (WRITE_FIRST or READ_FIRST configuration), the data-out busses reflect either the data-in busses or the stored value before write. During a write operation in NO_CHANGE mode, data-out busses are not affected. The regular data-out bus (DO) and the parity data-out bus (DOP) (when available) have a total width equal to the port width, as shown in Table 2-11.

Inverting Control Pins

For each port, the four control pins (CLK, EN, WE, and SSR) each have an individual inversion option. Any control signal can be configured as active High or Low, and the clock can be active on a rising or falling edge (active High on rising edge by default) without requiring other logic resources.

Unused Inputs

Non-connected Data and/or address inputs should be connected to logic “1”.

GSR

The global set/reset (GSR) signal of a Virtex-II device is an asynchronous global signal that is active at the end of device configuration. The GSR can also restore the initial Virtex-II state at any time. The GSR signal initializes the output latches to the INIT, or to the INIT_A and INIT_B value (see “Attributes” on page 205). A GSR signal has no impact on internal memory contents. Because it is a global signal, the GSR has no input pin at the functional level (block SelectRAM primitive).

Address Mapping

Each port accesses the same set of 18,432 memory cells using an addressing scheme dependent on the width of the port. The physical RAM locations addressed for a particular width are determined using the following formula (of interest only when the two ports use different aspect ratios):

```
END = ((ADDR + 1) * Width) -1 START= ADDR * Width
```

Table 2-12 shows low-order address mapping for each port width.

Table 2-12: **Port Address Mapping**

Port Width	Parity Locations	Data Locations																													
1	N.A.	31	30	29	28	27	26	25	24	23	22	21	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
2		15		14		13		12		11		10		9		8		7		6		5		4		3		2		1		0	
4		7				6				5				4				3				2				1				0	
8 + 1	3 2 1 0	3								2								1								0					
16 + 2	1 0	1																0													
32 + 4	0	0																													

Attributes

Content Initialization - INIT_xx

INIT_xx attributes define the initial memory contents. By default block SelectRAM memory is initialized with all zeros during the device configuration sequence. The 64 initialization attributes from INIT_00 through INIT_3F represent the regular memory contents. Each INIT_xx is a 64-digit hex-encoded bit vector. The memory contents can be partially initialized and are automatically completed with zeros.

The following formula is used for determining the bit positions for each INIT_xx attribute.

Given yy = conversion hex-encoded to decimal (xx), INIT_xx corresponds to the memory cells as follows:

- from [(yy + 1) * 256] -1
- to (yy) * 256

For example, for the attribute INIT_1F, the conversion is as follows:

- yy = conversion hex-encoded to decimal X"1F" = 31
- from [(31+1) * 256] -1 = 8191
- to 31 * 256 = 7936

More examples are given in Table 2-13.

Table 2-13: **Block SelectRAM Initialization Attributes**

Attribute	Memory Cell	
	from	to
INIT_00	255	0
INIT_01	511	256
INIT_02	767	512
…	…	…
INIT_0E	3839	3584
INIT_0F	4095	3840
INIT_10	4351	4096
…	…	…
INIT_1F	8191	7936
INIT_20	8447	8192
…	…	…
INIT_2F	12287	12032
INIT_30	12543	12288
..	…	…
INIT_3F	16383	16128

Content Initialization - INITP_xx

INITP_xx attributes define the initial contents of the memory cells corresponding to DIP/DOP busses (parity bits). By default these memory cells are also initialized to all zeros. The eight initialization attributes from INITP_00 through INITP_07 represent the memory contents of parity bits. Each INITP_xx is a 64-digit hex-encoded bit vector and behaves like a regular INIT_xx attribute. The same formula can be used to calculate the bit positions initialized by a particular INITP_xx attribute.

Output Latches Initialization - INIT (INIT_A & INIT_B)

The INIT (single-port) or INIT_A and INIT_B (dual-port) attributes define the output latches values after configuration. The width of the INIT (INIT_A & INIT_B) attribute is the port width, as shown in Table 2-14. These attributes are hex-encoded bit vectors and the default value is 0.

Output Latches Synchronous Set/Reset - SRVAL (SRVAL_A & SRVAL_B)

The SRVAL (single-port) or SRVAL_A and SRVAL_B (dual-port) attributes define output latch values when the SSR input is asserted. The width of the SRVAL (SRVAL_A and SRVAL_B) attribute is the port width, as shown in Table 2-14. These attributes are hex-encoded bit vectors and the default value is 0.

Table 2-14: **Port Width Values**

Port Data Width	DOP Bus	DO Bus	INIT / SRVAL
1	NA	<0>	1
2	NA	<1:0>	2
4	NA	<3:0>	4
9	<0>	<7:0>	(1+8) = 9
18	<1:0>	<15:0>	(2+16) = 18
36	<3:0>	<31:0>	(4 + 32) = 36

Initialization in VHDL or Verilog Codes

Block SelectRAM memory structures can be initialized in VHDL or Verilog code for both synthesis and simulation. For synthesis, the attributes are attached to the block SelectRAM instantiation and are copied in the EDIF output file to be compiled by Xilinx Alliance Series™ tools. The VHDL code simulation uses a `generic` parameter to pass the attributes. The Verilog code simulation uses a `defparam` parameter to pass the attributes.

The XC2V_RAMB_1_PORT block SelectRAM instantiation code examples (in VHDL and Verilog) illustrate these techniques (see "VHDL and Verilog Templates" on page 207).

Location Constraints

Block SelectRAM instances can have LOC properties attached to them to constrain placement. Block SelectRAM placement locations differ from the convention used for naming CLB locations, allowing LOC properties to transfer easily from array to array.

The LOC properties use the following form:

```
LOC = RAMB16_X#Y#
```

The RAMB16_X0Y0 is the bottom-left block SelectRAM location on the device.

Applications

Creating Larger RAM Structures

Block SelectRAM columns have specialized routing to allow cascading blocks with minimal routing delays. Wider or deeper RAM structures are achieved with a smaller timing penalty than is encountered when using normal routing resources.

The CORE Generator program offers the designer a painless way to generate wider and deeper memory structures using multiple block SelectRAM instances. This program outputs VHDL or Verilog instantiation templates and simulation models, along with an EDIF file for inclusion in a design.

Multiple RAM Organizations

The flexibility of block SelectRAM memories allows designs with various types of RAM in addition to regular configurations. Application notes at **www.xilinx.com** describe some of these designs, with VHDL and Verilog reference designs included.

Virtex-II block SelectRAM can be used as follows:

- Two independent single-port RAM resources
- One 72-bit single-port RAM resource
- One triple-port (1 Read/Write and 2 Read ports) RAM resource

Application notes with VHDL and Verilog reference designs at **www.xilinx.com** also describe other implementations using block SelectRAM memory, such as:

- **xapp258** "FIFOs Using Virtex-II Block RAM"
- **xapp260** "Fast Read/Write CAM Solution"

VHDL and Verilog Templates

VHDL and Verilog templates are available for all single-port and dual-port primitives. The A and B numbers indicate the width of the ports.

The following are single-port templates:

- SelectRAM_A1
- SelectRAM_A2
- SelectRAM_A4
- SelectRAM_A9
- SelectRAM_A18
- SelectRAM_A36

The following are dual-port templates:

- SelectRAM_A1_B1
- SelectRAM_A1_B2
- SelectRAM_A1_B4
- SelectRAM_A1_B9
- SelectRAM_A1_B18
- SelectRAM_A1_B36
- SelectRAM_A2_B2
- SelectRAM_A2_B4
- SelectRAM_A2_B9
- SelectRAM_A2_B18
- SelectRAM_A2_B36
- SelectRAM_A4_B4

- SelectRAM_A4_B9
- SelectRAM_A4_B18
- SelectRAM_A4_B36
- SelectRAM_A9_B9
- SelectRAM_A9_B18
- SelectRAM_A9_B36
- SelectRAM_A18_B18
- SelectRAM_A18_B36
- SelectRAM_A36_B36

VHDL Template

As an example, the **XC2V_RAMB_1_PORT.vhd** file uses the SelectRAM_A36 template:

```
-- Module: XC2V_RAMB_1_PORT
-- Description: 18Kb Block SelectRAM example
-- Single Port 512 x 36 bits
-- Use template "SelectRAM_A36.vhd"
--
-- Device: Virtex-II Family
----------------------------------------------------------------------
library IEEE;
use IEEE.std_logic_1164.all;
--
-- Syntax for Synopsys FPGA Express
-- pragma translate_off
library UNISIM;
use UNISIM.VCOMPONENTS.ALL;
-- pragma translate_on
--
entity XC2V_RAMB_1_PORT is
   port (
    DATA_IN : in std_logic_vector (35 downto 0);
        ADDRESS   : in std_logic_vector (8 downto 0);
        ENABLE: in std_logic;
        WRITE_EN     : in std_logic;
        SET_RESET    : in std_logic;
        CLK    : in std_logic;
        DATA_OUT     : out std_logic_vector (35 downto 0)
       );
end XC2V_RAMB_1_PORT;
--
architecture XC2V_RAMB_1_PORT_arch of XC2V_RAMB_1_PORT is
--
-- Components Declarations:
--
component BUFG
  port (
  I : in std_logic;
  O : out std_logic
  );
end component;
--
-- Syntax for Synopsys FPGA Express
component RAMB16_S36
-- pragma translate_off
  generic (
-- "Read during Write" attribute for functional simulation
  WRITE_MODE : string := "READ_FIRST" ; -- WRITE_FIRST(default)/
READ_FIRST/ NO_CHANGE
```

```
-- Output value after configuration
  INIT : bit_vector(35 downto 0)  := X"000000000";
-- Output value if SSR active
  SRVAL : bit_vector(35 downto 0)  := X"012345678";
-- Plus bits initial content
       INITP_00 : bit_vector(255 downto 0) :=
X"0000000000000000000000000000000000000000000000000FEDCBA9876543210";
       INITP_01 : bit_vector(255 downto 0) :=
X"0000000000000000000000000000000000000000000000000000000000000000";
       INITP_02 : bit_vector(255 downto 0) :=
X"0000000000000000000000000000000000000000000000000000000000000000";
       INITP_03 : bit_vector(255 downto 0) :=
X"0000000000000000000000000000000000000000000000000000000000000000";
       INITP_04 : bit_vector(255 downto 0) :=
X"0000000000000000000000000000000000000000000000000000000000000000";
       INITP_05 : bit_vector(255 downto 0) :=
X"0000000000000000000000000000000000000000000000000000000000000000";
       INITP_06 : bit_vector(255 downto 0) :=
X"0000000000000000000000000000000000000000000000000000000000000000";
       INITP_07 : bit_vector(255 downto 0) :=
X"0000000000000000000000000000000000000000000000000000000000000000";
-- Regular bits initial content
       INIT_00 : bit_vector(255 downto 0) :=
X"0000000000000000000000000000000000000000000000000FEDCBA9876543210";
       INIT_01 : bit_vector(255 downto 0) :=
X"0000000000000000000000000000000000000000000000000000000000000000";
       INIT_02 : bit_vector(255 downto 0) :=
X"0000000000000000000000000000000000000000000000000000000000000000";
       ... (cut)
       INIT_3E : bit_vector(255 downto 0) :=
X"0000000000000000000000000000000000000000000000000000000000000000";
       INIT_3F : bit_vector(255 downto 0) :=
X"0000000000000000000000000000000000000000000000000000000000000000"
  );
-- pragma translate_on
  port (
        DI     : in std_logic_vector (31 downto 0);
        DIP    : in std_logic_vector (3 downto 0);
        ADDR   : in std_logic_vector (8 downto 0);
        EN     : in STD_LOGIC;
        WE     : in STD_LOGIC;
        SSR    : in STD_LOGIC;
        CLK    : in STD_LOGIC;
        DO     : out std_logic_vector (31 downto 0);
        DOP    : out std_logic_vector (3 downto 0)
  );
end component;
--
-- Attribute Declarations:
attribute WRITE_MODE : string;
attribute INIT: string;
attribute SRVAL: string;
--
attribute INITP_00: string;
attribute INITP_01: string;
attribute INITP_02: string;
attribute INITP_03: string;
attribute INITP_04: string;
attribute INITP_05: string;
attribute INITP_06: string;
attribute INITP_07: string;
--
```

```
attribute INIT_00: string;
attribute INIT_01: string;
attribute INIT_02: string;
… (cut)
attribute INIT_3E: string;
attribute INIT_3F: string;
--
-- Attribute "Read during Write mode" = WRITE_FIRST(default)/
READ_FIRST/ NO_CHANGE
attribute WRITE_MODE of U_RAMB16_S36: label is "READ_FIRST";
attribute INIT of U_RAMB16_S36: label is "000000000";
attribute SRVAL of U_RAMB16_S36: label is "012345678";
--
-- RAMB16 memory initialization for Alliance
-- Default value is "0" / Partial initialization strings are padded
-- with zeros to the left
attribute INITP_00 of U_RAMB16_S36: label is
"0000000000000000000000000000000000000000000000000FEDCBA9876543210";
attribute INITP_01 of U_RAMB16_S36: label is
"0000000000000000000000000000000000000000000000000000000000000000";
attribute INITP_02 of U_RAMB16_S36: label is
"0000000000000000000000000000000000000000000000000000000000000000";
attribute INITP_03 of U_RAMB16_S36: label is
"0000000000000000000000000000000000000000000000000000000000000000";
attribute INITP_04 of U_RAMB16_S36: label is
"0000000000000000000000000000000000000000000000000000000000000000";
attribute INITP_05 of U_RAMB16_S36: label is
"0000000000000000000000000000000000000000000000000000000000000000";
attribute INITP_06 of U_RAMB16_S36: label is
"0000000000000000000000000000000000000000000000000000000000000000";
attribute INITP_07 of U_RAMB16_S36: label is
"0000000000000000000000000000000000000000000000000000000000000000";
--
attribute INIT_00 of U_RAMB16_S36: label is
"0000000000000000000000000000000000000000000000000FEDCBA9876543210";
attribute INIT_01 of U_RAMB16_S36: label is
"0000000000000000000000000000000000000000000000000000000000000000";
attribute INIT_02 of U_RAMB16_S36: label is
"0000000000000000000000000000000000000000000000000000000000000000";
... (cut)
attribute INIT_3E of U_RAMB16_S36: label is
"0000000000000000000000000000000000000000000000000000000000000000";
attribute INIT_3F of U_RAMB16_S36: label is
"0000000000000000000000000000000000000000000000000000000000000000";
--
--
-- Signal Declarations:
--
-- signal VCC : std_logic;
-- signal GND : std_logic;
signal CLK_BUFG: std_logic;
signal INV_SET_RESET : std_logic;
--
begin
-- VCC <= '1';
-- GND <= '0';
--
-- Instantiate the clock Buffer
U_BUFG: BUFG
  port map (
  I => CLK,
  O => CLK_BUFG
```

```
  );
--
-- Use of the free inverter on SSR pin
INV_SET_RESET <= NOT SET_RESET;

-- Block SelectRAM Instantiation
U_RAMB16_S36: RAMB16_S36
  port map (
        DI     => DATA_IN (31 downto 0), -- insert 32 bits data-in bus
(<31 downto 0>)
        DIP    => DATA_IN (35 downto 32), -- insert 4 bits parity data-
in bus (or <35 downto 32>)
       ADDR   => ADDRESS (8 downto 0), -- insert 9 bits address bus
         EN     => ENABLE, -- insert enable signal
         WE     => WRITE_EN, -- insert write enable signal
         SSR    => INV_SET_RESET, -- insert set/reset signal
         CLK    => CLK_BUFG, -- insert clock signal
        DO     => DATA_OUT (31 downto 0), -- insert 32 bits data-out bus
(<31 downto 0>)
        DOP    => DATA_OUT (35 downto 32)  -- insert 4 bits parity data-
out bus (or <35 downto 32>)
  );
--
end XC2V_RAMB_1_PORT_arch;
----------------------------------------------------------------------
```

Verilog Template

```
// Module: XC2V_RAMB_1_PORT
// Description: 18Kb Block SelectRAM-II example
//  Single Port 512 x 36 bits
//  Use template "SelectRAM_A36.v"
//
// Device: Virtex-II Family
//----------------------------------------------------------------------

module XC2V_RAMB_1_PORT (CLK, SET_RESET, ENABLE, WRITE_EN, ADDRESS,
DATA_IN, DATA_OUT);


input CLK, SET_RESET, ENABLE, WRITE_EN;
input [35:0] DATA_IN;
input [8:0] ADDRESS;
output [35:0] DATA_OUT;

wire CLK_BUFG, INV_SET_RESET;

//Use of the free inverter on SSR pin
assign INV_SET_RESET = ~SET_RESET;


// initialize block ram for simulation
// synopsys translate_off
defparam
  //"Read during Write" attribute for functional simulation
  U_RAMB16_S36.WRITE_MODE = "READ_FIRST",   //WRITE_FIRST(default)/
READ_FIRST/ NO_CHANGE
  //Output value after configuration
  U_RAMB16_S36.INIT = 36'h000000000,
  //Output value if SSR active
  U_RAMB16_S36.SRVAL = 36'h012345678,
```

```
  //Plus bits initial content
  U_RAMB16_S36.INITP_00 =
256'h0123456789ABCDEF0000000000000000000000000000000000000000000000000000,
  U_RAMB16_S36.INITP_01 =
256'h0000000000000000000000000000000000000000000000000000000000000000000,
  U_RAMB16_S36.INITP_02 =
256'h0000000000000000000000000000000000000000000000000000000000000000000,
  U_RAMB16_S36.INITP_03 =
256'h0000000000000000000000000000000000000000000000000000000000000000000,
  U_RAMB16_S36.INITP_04 =
256'h0000000000000000000000000000000000000000000000000000000000000000000,
  U_RAMB16_S36.INITP_05 =
256'h0000000000000000000000000000000000000000000000000000000000000000000,
  U_RAMB16_S36.INITP_06 =
256'h0000000000000000000000000000000000000000000000000000000000000000000,
  U_RAMB16_S36.INITP_07 =
256'h0000000000000000000000000000000000000000000000000000000000000000000,

  //Regular bits initial content
  U_RAMB16_S36.INIT_00 =
256'h0123456789ABCDEF0000000000000000000000000000000000000000000000000000,
  U_RAMB16_S36.INIT_01 =
256'h0000000000000000000000000000000000000000000000000000000000000000000,
  U_RAMB16_S36.INIT_02 =
256'h0000000000000000000000000000000000000000000000000000000000000000000,
...<cut>
  U_RAMB16_S36.INIT_3E =
256'h0000000000000000000000000000000000000000000000000000000000000000000,
  U_RAMB16_S36.INIT_3F =
256'h0000000000000000000000000000000000000000000000000000000000000000000;
 // synopsys translate_on

//Instantiate the clock Buffer
BUFG U_BUFG (  .I(CLK), .O(CLK_BUFG));

//Block SelectRAM Instantiation
RAMB16_S36 U_RAMB16_S36 (   .DI(DATA_IN[31:0]),
          .DIP(DATA_IN-PARITY[35:32]),
          .ADDR(ADDRESS),
          .EN(ENABLE),
          .WE(WRITE_EN),
          .SSR(INV_SET_RESET),
          .CLK(CLK_BUFG),
          .DO(DATA_OUT[31:0]),
          .DOP(DATA_OUT-PARITY[35:32]));

// synthesis attribute declarations
  /* synopsys attribute

  WRITE_MODE "READ_FIRST"
  INIT "000000000"
  SRVAL "012345678"

  INITP_00
"0123456789ABCDEF0000000000000000000000000000000000000000000000000000"
  INITP_01
"0000000000000000000000000000000000000000000000000000000000000000000"
  INITP_02
"0000000000000000000000000000000000000000000000000000000000000000000"
  INITP_03
"0000000000000000000000000000000000000000000000000000000000000000000"
```

```
  INITP_04
"0000000000000000000000000000000000000000000000000000000000000000"
  INITP_05
"0000000000000000000000000000000000000000000000000000000000000000"
  INITP_06
"0000000000000000000000000000000000000000000000000000000000000000"
  INITP_07
"0000000000000000000000000000000000000000000000000000000000000000"

  INIT_00
"0123456789ABCDEF0000000000000000000000000000000000000000000000000"
  INIT_01
"0000000000000000000000000000000000000000000000000000000000000000"
  INIT_02
"0000000000000000000000000000000000000000000000000000000000000000"
...<cut>
  INIT_3E
"0000000000000000000000000000000000000000000000000000000000000000"
  INIT_3F
"0000000000000000000000000000000000000000000000000000000000000000"
  */

endmodule
```